

FRED Pt® Gen 4 Single Ultrafast Diode, 500 A (INT-A-PAK Power Modules)



INT-A-PAK

PRIMARY CHARACTERISTICS					
V_{R}	600 V				
I _{F(AV)} at T _C	500 A at 55 °C				
t _{rr} at 25 °C	104 ns				
Туре	Modules - diode, FRED Pt®				
Package	INT-A-PAK				
Circuit configuration	Single diode				

FEATURES

- Gen 4 FRED Pt[®] dices technology
- Ultrasoft reverse recovery characteristics
- Low I_{RRM} and reverse recovery charge
- · Very low forward voltage drop
- 175 °C operating junction temperature
- UL approved file E78996 for application with maximum case temperature up to 140 °C
- · Large creepage distances
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

Gen 4 FRED Pt technology, state of the art, ultra low V_F , soft switching optimized for IGBT F/W diode.

The minimized conduction loss, optimized storage charge, and low recovery current, minimized the switching losses and reduce the over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		600	V
Continuous forward current	I _F	T _C = 25 °C	772	
Continuous forward current		T _C = 90 °C	519	A
Single pulse forward current	I _{FSM}	t_p = 10 ms, 50 Hz, sine half wave, initial T_J = 175 °C	4500	
Maximum power dissipation	P _D	T _C = 25 °C	1363	W
		T _C = 90 °C	772	VV
Operating junction temperature range	TJ		-40 to +175	°C
Storage temperature range	T _{Stg}		-40 to +150	C
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted, t = 1 s	3500	V

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 500 μA	600	-	-	
Forward voltage drop	V _{FM}	I _F = 250 A	-	1.25	-	
		I _F = 500 A	-	1.45	1.66	V
		I _F = 250 A, T _J = 150 °C	-	1.23	-	
		I _F = 500 A, T _J = 150 °C	-	1.0	-	
Reverse leakage current	I _{RM}	V _R = 600 V	-	2.0	200	μΑ
		T _J = 150 °C, V _R = 600 V	-	1.8	-	mA



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
B	+	T _J = 25 °C	I _F = 150 A dl/dt = 1000 A/μs V _R = 300 V	-	104	-	- ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	193	-	
Dools woody on a current	Peak recovery current I _{rr}	T _J = 25 °C		-	59	-	Α
Peak recovery current		T _J = 125 °C		-	122	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	3.5	-	μС
		T _J = 125 °C		-	13.8	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	-	-	0.11	K/W
Typical thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.035	-	r√ vv
Mounting to heat sink busbar		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4	1	6	Nm
Approximate weight			-	200	-	g
Approximate weight			-	7.1	-	OZ.
Case style				INT-A	N-PAK	•

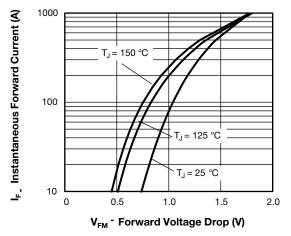


Fig. 1 - Typical Forward Voltage Drop Characteristics

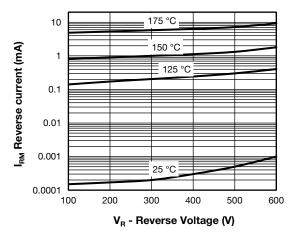


Fig. 2 - Typical Value of Reverse Current vs. Reverse Voltage

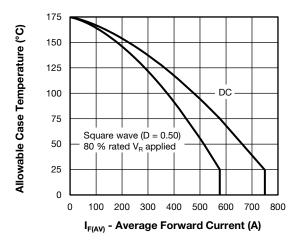


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

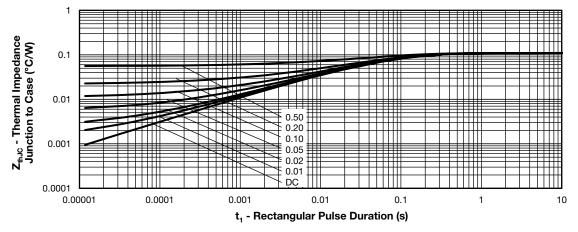


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

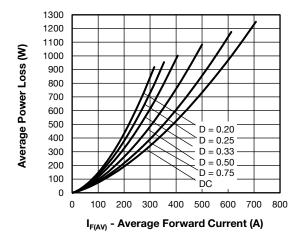


Fig. 5 - Forward Power Loss Characteristics

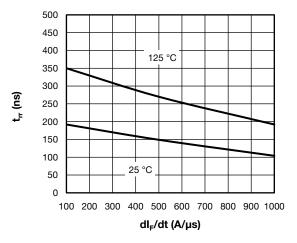


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 300 \text{ V}$

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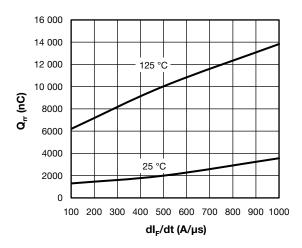


Fig. 7 - Typical Reverse Recovery Charge vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 300 \text{ V}$

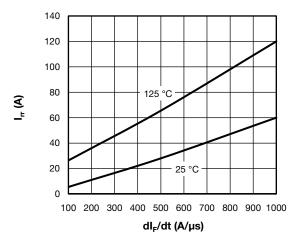
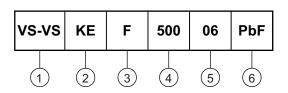


Fig. 8 - Typical Reverse Recovery Current vs. dI_F/dt $I_{FM} = 150 \text{ A}, V_R = 300 \text{ V}$

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Circuit configuration: KE = single diode

3 - F = FRED Pt® ultrafast diode

Current rating (500 = 500 A)

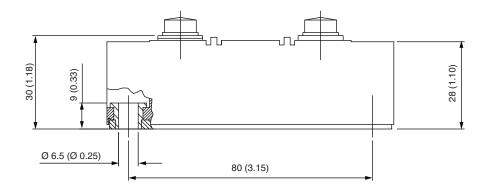
5 - Voltage rating (06 = 600 V)

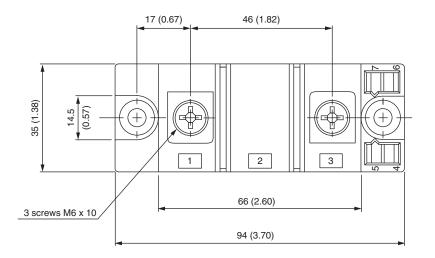
6 - PbF = lead (Pb)-free

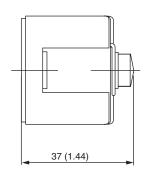
CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Single diode	KE	(3) O ~ O+ (1)				



DIMENSIONS in millimeters (inches)



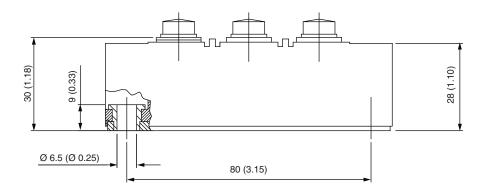


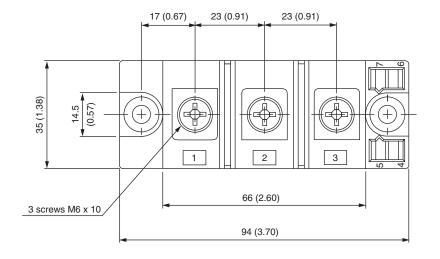


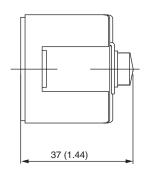


INT-A-PAK DBC

DIMENSIONS in millimeters (inches)









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